RENESAS QUICKSWITCH[®] PRODUCTS HIGH-SPEED CMOS QUADRUPLE BUS SWITCH WITH INDIVIDUAL ACTIVE HIGH ENABLES

FEATURES:

- · Enhanced N channel FET with no inherent diode to Vcc
- · Bidirectional switches connect inputs to outputs
- Pin compatible with the 74'126 function
- · Zero propagation delay, zero ground bounce
- · Undershoot clamp diodes on all switch and control inputs
- · Available in QSOP and SOIC packages

APPLICATIONS:

- · Active high enabling
- · Hot-swapping, hot-docking
- Voltage translation (5V to 3.3V)
- · Power conservation
- Capacitance reduction and isolation (mass storage, work stations)
- Logic replacement (data processing)
- Clock gating
- Bus isolation

FUNCTIONAL BLOCK DIAGRAM

10E

20E

DESCRIPTION:

1A

2A

ЗA

3Y

4Y

4A

The QS3126 provides a set of four high-speed CMOS switches connecting inputs to outputs. The low ON resistance of the QS3126 allows inputs to be connected to outputs without propagation delay and without generating additional ground bounce noise. Individual active high enables (OE) are used to turn the switches on. The QS3126 is ideal for signal and control switching since the device adds no noise, ground bounce, propagation delay, or significant power consumption to the system.

QuickSwitch devices provide an order of magnitude faster speed than conventional logic devices.

The QS3126 is characterized for operation at -40°C to +85°C.

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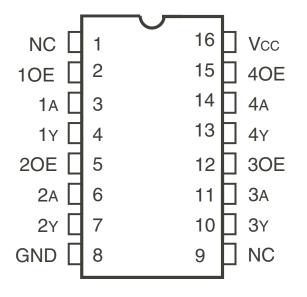
INDUSTRIAL TEMPERATURE RANGE

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HIGH-SPEED CMOS QUADRUPLE BUS SWITCH WITH INDIVIDUAL ACTIVE

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PINCONFIGURATION



TOP VIE	w
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Package Type	Package Code	Order Code
QSOP	PCG16	QG

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

Symbol	Description	Max	Unit
VTERM ⁽²⁾	Supply Voltage to Ground	–0.5 to +7	V
VTERM ⁽³⁾	DC Switch Voltage Vs	–0.5 to +7	V
VTERM ⁽³⁾	DC Input Voltage VIN	–0.5 to +7	V
VAC	AC Input Voltage (pulse width ≤20ns)	-3	V
Ιουτ	DC Output Current	120	mA
Рмах	Maximum Power Dissipation (TA = 85°C)	0.5	W
Tstg	Storage Temperature	-65 to +150	°C

NOTES:

 Stresses greater than those listed under ABSOLUTE MAXIMUM RATINGS may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

2. Vcc terminals.

3. All terminals except Vcc .

CAPACITANCE (TA = $+25^{\circ}$ C, f = 1MHz, VIN = 0V, VOUT = 0V)

Pins	Тур.	Max. ⁽¹⁾	Unit
Control Inputs	3	5	рF
Quickswitch Channels (Switch OFF)	5	7	pF

NOTE:

1. This parameter is guaranteed but not production tested.

PIN DESCRIPTION

Pin Names	I/O	Description		
1a - 4a	I/O	Bus A		
1y - 4y	I/O	Bus Y		
10E - 40E	Ι	Bus Switch Enable		



xOE	хА	хҮ	Function	
Н	Н	Н	Connect	
Н	L	L	Connect	
L	Х	Х	Disconnect	

NOTE:

1. H = HIGH Voltage Level

L = LOW Voltage Level

X = Don't Care

10E 🗌		14	Vcc
1a 🗌	2	13	_ 40E
1Y 🗌	3	12	4A
20E 🗌	4	11	4Y
2a 🗌	5	10] 30E
2Y 🗌	6	9	3A
GND	7	8	3Y

	TOP VIEW	
Package Type	Package Code	Order Code
SOIC	DCG14	S1G



QS3126 HIGH-SPEED CMOS QUADRUPLE BUS SWITCH WITH INDIVIDUAL ACTIVE

DC ELECTRICAL CHARACTERISTICS OVER OPERATING RANGE

Following Conditions Apply Unless Otherwise Specified: Industrial: TA = -40° C to $+85^{\circ}$ C, VCC = 5V \pm 5%

Symbol	Parameter	Test Conditions	Min.	Тур. ⁽¹⁾	Max.	Unit
Vih	Input HIGH Voltage	Guaranteed Logic HIGH for Control Inputs	2	—	_	V
Vil	Input LOW Voltage	Guaranteed Logic LOW for Control Inputs	—	-	0.8	V
lin	Input Leakage Current (Control Inputs)	$0V \le VIN \le VCC$	_	—	±1	μA
loz	Off-State Current (Hi-Z)	$0V \le VOUT \le VCC$, Switches OFF	—	—	±1	μA
Ron	Switch ON Resistance ⁽²⁾	VCC = Min., VIN = 0V, ION = 30mA	-	5	7	Ω
		VCC = Min., VIN = 2.4V, ION = 15mA	_	10	15	
Vp	Pass Voltage ⁽³⁾	$VIN = VCC = 5V$, $IOUT = -5\mu A$	3.7	4	4.2	V

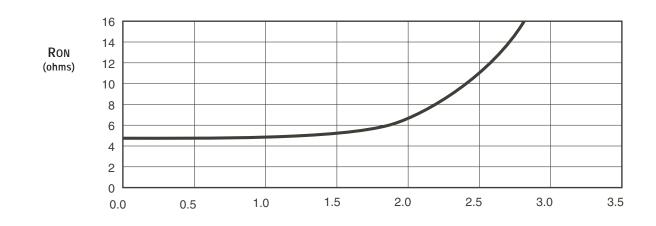
NOTES:

1. Typical values are at Vcc = 5V and TA = 25° C.

2. Ron is guaranteed but not production tested.

3. Pass voltage is guaranteed but not production tested.

TYPICAL ON RESISTANCE vs VIN AT VCC = 5V



VIN (Volts)



QS3126 HIGH-SPEED CMOS QUADRUPLE BUS SWITCH WITH INDIVIDUAL ACTIVE

POWER SUPPLY CHARACTERISTICS

Symbol	Parameter	Test Conditions ⁽¹⁾		Unit
lcco	Quiescent Power Supply Current	Vcc = Max., VIN = GND or Vcc, f = 0	3	μA
ΔICC	Power Supply Current per Input HIGH ⁽²⁾	Vcc = Max., VIN = 3.4V, f = 0	1.25	mA
ICCD	Dynamic Power Supply Current per MHz $^{\scriptscriptstyle (3)}$	Vcc = Max., A and Y Pins Open, Control Inputs Toggling @ 50% Duty Cycle	0.25	mA/MHz

NOTES:

1. For conditions shown as Min. or Max., use the appropriate values specified under DC Electrical Characteristics.

2. Per TTL-driven input (VIN = 3.4V, control inputs only). A and Y pins do not contribute to Δ Icc.

3. This current applies to the control inputs only and represents the current required to switch internal capacitance at the specified frequency. The A and Y inputs generate no significant AC or DC currents as they transition. This parameter is guaranteed but not production tested.

SWITCHING CHARACTERISTICS OVER OPERATING RANGE

 $T_{A} = -40^{\circ}C \text{ to } +85^{\circ}C, V_{CC} = 5V \pm 5\%$

CLOAD = 50pF, RLOAD = 500Ω unless otherwise noted.

Symbol	Parameter	Min. ⁽¹⁾	Тур.	Max.	Unit
tplh tphl	Data Propagation Delay ⁽²⁾ A to Y	—	_	0.25 ⁽³⁾	ns
tPZL tPZH	Switch Turn-On Delay OE_to_xA/xY	1.5		6.5	ns
tplz tphz	Switch Turn-Off Delay ⁽²⁾ OE to xA/xY	1.5		5.5	ns

NOTES:

1. Minimums are guaranteed but not production tested.

2. This parameter is guaranteed but not production tested.

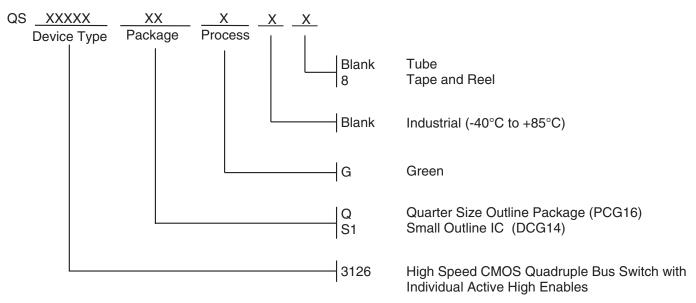
3. The bus switch contributes no propagation delay other than the RC delay of the ON resistance of the switch and the load capacitance. The time constant for the switch alone is of the order of 0.25ns at CL = 50pF. Since this time constant is much smaller than the rise and fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the bus switch, when used in a system, is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

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INDUSTRIALTEMPERATURERANGE

ORDERING INFORMATION



Orderable Part Information

Speed (ns)	Orderable Part ID	Pkg. Code	Pkg. Type	Temp. Grade
	QS3126QG	PCG16	QSOP	I
	QS3126QG8	PCG16	QSOP	I
	QS3126S1G	DCG14	SOIC	I
	QS3126S1G8	DCG14	SOIC	I

Datasheet Document History

02/08/2011	Pg. 5	Updated the ordering information by removing the "IDT" notation, non RoHS part and by adding
		Tape and Reel information.
06/02/2011	Pg. 1,2	Corrected \overline{OE} to OE as in previous revision.
05/06/2019	Pg. 2,6	Added table under pin configuration diagram with detailed package information and orderable part information table.
	Ũ	Updated the ordering information diagram in clearer detail.